

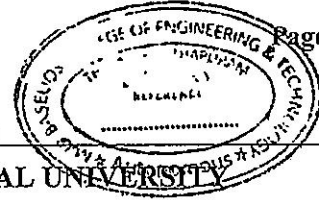
H1

02000ECT292072101

Pages: 2

Reg No.: _____

Name: _____



APJ ABDUL KALAM TECHNOLOGICAL UNIVERSITY

Fourth Semester B.Tech (Hons) Degree Examination July 2021 (2019 admission)

Course Code: ECT292

Course Name: NANO ELECTRONICS

Max. Marks: 100

Duration: 3 Hours

PART A

(Answer all questions; each question carries 3 marks)

		Marks
1	Explain any two characteristic lengths associated with a mesoscopic system	(3)
2	Explain the features of parabolic quantum wells	(3)
3	DC sputtering cannot be used for coating non conducting materials. Justify	(3)
4	Illustrate effusion cells used in molecular beam epitaxy.	(3)
5	Compare electron microscope and optical microscope.	(3)
6	Draw the figure showing specimen interaction of Scanning Electron Microscope.	(3)
7	Explain modulation doped quantum wells, with the aid of energy band diagram.	(3)
8	Explain the concept of hot electrons in parallel transport	(3)
9	Explain resonant tunnelling effect.	(3)
10	List any six properties of Graphene.	(3)

PART B

(Answer one full question from each module, each question carries 14 marks)

Module -1

- | | | |
|----|--|-----|
| 11 | a) Derive the expression for density of states in a 1D nano material | (9) |
| | b) Consider an electron having kinetic energy 5eV and effective mass $0.511m_0$. Calculate its De-Broglie wavelength. If the size of the measoscopic structure having this electron is in the range of $2 \times 10^{-14}m$, will it fall in the category of nanostructures? | (5) |
| 12 | a) Explain the physical limitations in reducing the size of devices in Nano scale. | (6) |
| | b) Explain the classifications of the nanostructures in detail | (8) |

02000ECT292072101

Module -2

- 13 a) Explain the different steps involved in a CVD technique for fabricating nano layers. (9)
b) Explain reduction method for fabricating metallic nano particles (5)
- 14 a) Explain sol-gel process for fabrication of nano-particles. (9)
b) Explain laser beam ablation method for fabricating nano layers (5)

Module -3

- 15 a) Illustrate the principle of imaging using STM (9)
b) Explain the working of XRD analyzer and how it can be used to analyze a crystal. (5)
- 16 Explain the principle of operation and operating modes of AFM (14)

Module -4

- 17 (a) Explain coulomb blockade effect. Explain the conditions to be satisfied to observe coulomb blockade effect (10)
(b) Compare MQW with superlattice structure. (4)
- 18 a) Explain resonant tunnelling effect in quantum structure. (8)
b) Explain the Shubnikov-de Hass effect of magnetic fields in 2D systems. (6)

Module -5

- 19 a) Draw the schematic and explain the working of a single electron transistor (8)
b) Explain Hot Electron Transistors (6)
- 20 a) With the help of a neat schematic diagram explain MODFETs. (8)
b) Illustrate the working of Quantum dot laser. (6)

